

TCA9617B Level-Translating FM+ I²C Bus Repeater

1 Features

- Two-channel bidirectional I²C buffer
- Support for standard mode, fast mode (400kHz), and fast mode+ (1MHz) I²C operation
- Operating supply voltage range of 0.8V to 5.5V on A-side
- Operating supply voltage range of 2.2V to 5.5V on B-side
- Voltage-level translation from 0.8V to 5.5V and 2.2V to 5.5V
- Footprint and function replacement for TCA9517
- Active-high repeater-enable input
- Open-drain I²C I/O
- 5.5V Tolerant I²C and enable input support
- Lockup-free operation
- Powered-off high-impedance I²C bus pins
- Support for clock stretching and multiple controller arbitration across the device
- Latch-up performance exceeds 100mA per JESD 78, class II
- ESD protection exceeds JESD 22
 - 4000V Human-body model
 - 1500V Charged-device model

2 Applications

- [Servers](#)
- [Routers](#) (Telecom Switching Equipment)
- [Industrial Equipment](#)
- Products with many I²C targets and/or long PCB traces

3 Description

The TCA9617B is a BiCMOS dual bidirectional buffer intended for I²C bus and SMBus systems. The device provides bidirectional voltage-level translation (up-translation and down-translation) between low voltages (down to 0.8V) and higher voltages (2.2V to 5.5V) in mixed-mode applications. This device enables I²C and similar bus systems to be extended, without degradation of performance even during level shifting.

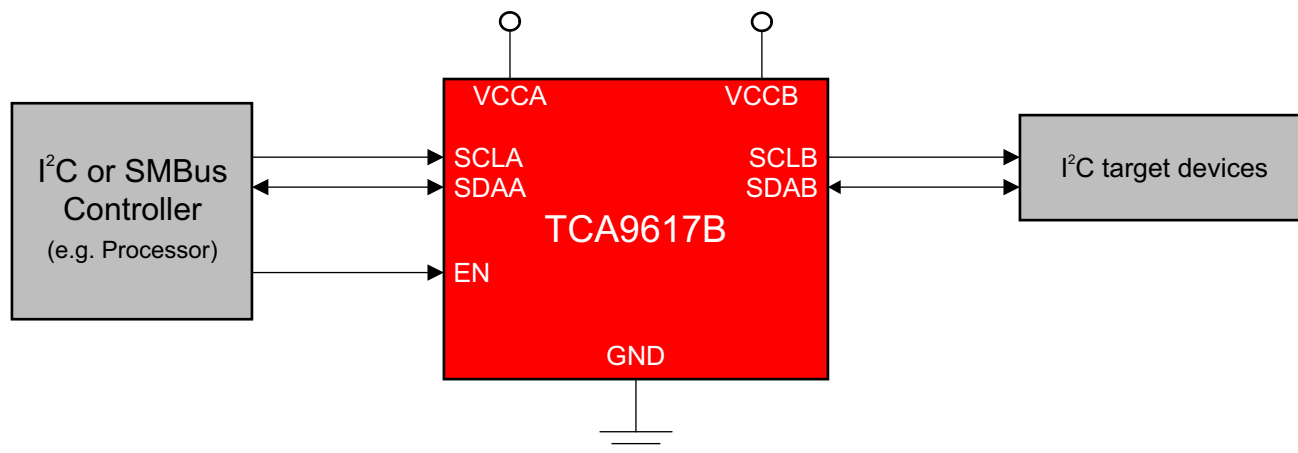
The TCA9617B buffers both the serial data (SDA) and the serial clock (SCL) signals on the I²C bus, allowing two buses of 550pF to be connected in an I²C application. This device can also be used to separate two halves of a bus for voltage and capacitance.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
TCA9617B	VSSOP (8)	3mm × 3mm

(1) For more information, see [Section 10](#).

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



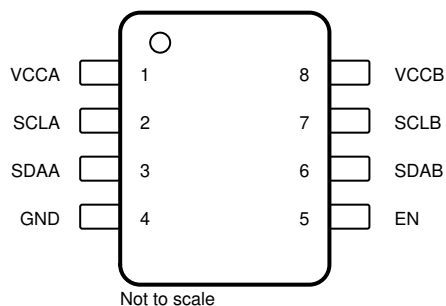
Simplified Schematic



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4 Pin Configuration and Functions



**Figure 4-1. DGK Package, 8-Pin VSSOP
(Top View)**

Table 4-1. Pin Functions

PIN		DESCRIPTION
NAME	NO.	
VCCA	1	A-side supply voltage (0.8V to 5.5V)
SCLA	2	I ² C SCL line, A side. Connect to V _{CCA} through a pull-up resistor.
SDAA	3	I ² C SDA line, A side. Connect to V _{CCA} through a pull-up resistor.
GND	4	Supply ground
EN	5	Active-high repeater enable input. Internally connected to V _{CCB} through a weak pull-up resistor.
SDAB	6	I ² C SDA line, B side. Connect to V _{CCB} through a pull-up resistor.
SCLB	7	I ² C SCL line, B side. Connect to V _{CCB} through a pull-up resistor.
VCCB	8	B-side and device supply voltage (2.2V to 5.5V)

5 Specifications

5.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CCB}	Supply voltage range		−0.5	6.5	V
V _{CCA}	Supply voltage range		−0.5	6.5	V
V _I	Enable input voltage range ⁽²⁾		−0.5	6.5	V
V _{IO}	I ² C bus voltage range ⁽²⁾		−0.5	6.5	V
I _{IK}	Input clamp current	V _I < 0		−50	mA
I _{OK}	Output clamp current	V _O < 0		−50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CC} or GND			±100	mA
T _{stg}	Storage temperature		−65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±4000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	Supply voltage, A-side bus		0.8	V _{CCB}	V
V _{CCB}	Supply voltage, B-side bus		2.2	5.5	V
I _{OLA}	Low-level output current			30	mA
I _{OLB}	Low-level output current		0.1	30	mA
T _A	Ambient temperature		−40	85	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DGK	UNIT
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	171.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	77.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	107.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	12.3	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	105.3	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics

$V_{CCB} = 2.2V$ to $5.5V$, $GND = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS	V_{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}	Input clamp voltage		$I_I = -18mA$	2.2V to 5.5V	-1.2		0	V
V_{OL}	Low-level output voltage	SDAB, SCLB	$I_{OL} = 100\mu A$ or $30mA$, $V_{ILA} = 0V$	2.2V to 5.5V	0.48	0.53	0.58	V
		SDAA, SCLA	$I_{OL} = 30mA$			0.1	0.23	
V_{IH}	High-level input voltage	SDAA, SCLA		2.2V to 5.5V	$0.7 \times V_{CCA}$		5.5	V
		SDAB, SCLB			$0.7 \times V_{CCA}$		5.5	
		EN			$0.7 \times V_{CCB}$		5.5	
V_{IL}	Low-level input voltage	SDAA, SCLA		2.2V to 5.5V			$0.3 \times V_{CCA}$	V
		SDAB, SCLB					0.4	
		EN					$0.3 \times V_{CCB}$	
I_{CCA}	Quiescent supply current for V_{CCA}		Both channels low, SDAA = SCLA = GND and $I_{OLB} = 100\mu A$, or SDAA = SCLA = open and SDAB = SCLB = GND	2.2V to 5.5V			13	μA
I_{CCB}	Quiescent supply current		Both Channels high, SDAA = SCLA = VCCA B-side pulled up to VCCB with pull-up resistors	2.2V to 5.5V		4.5	7	mA
			Both channels low, SDAA = SCLA = GND, $I_{OLB} = 100\mu A$	5.5V		5.7	8.1	

5.5 Electrical Characteristics (continued)

$V_{CCB} = 2.2V$ to $5.5V$, $GND = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS	V_{CCB}	MIN	TYP ⁽¹⁾	MAX	UNIT
I_I	Input leakage current	SDAB, SCLB	$V_I = V_{CCB}$	2.2V to 5.5V	–1		1	μA
			$V_I = 0.2V$, $EN = 0$		–10		10	
			$V_I = V_{CCB} - 0.2V$		–1		1	
			$V_I = 5.5V$, $V_{CCA} = 0V$	0V	–10		10	
		SDAA, SCLA	$V_I = V_{CCA}$	2.2V to 5.5V	–1		1	
			$V_I = 0.2V$, $EN = 0$		–10		10	
			$V_I = V_{CCA} - 0.2V$		–1		1	
			$V_I = 5.5V$, $V_{CCA} = 0V$	0V	–10		10	
C_I	Input capacitance	EN	$V_I = V_{CCB}$	3.3V	–1		1	pF
			$V_I = 0.2V$		–25			
C_{IO}	Input/output capacitance	SCLA, SDAA	$V_I = 3V$ or $0V$	3.3V			9	pF
				0V			9	
		SCLB, SDAB	$V_I = 3V$ or $0V$	3.3V			14	
				0V			14	

(1) All typical values are at $T_A = 25^{\circ}C$.

5.6 Timing Requirements

$V_{CCA} = 0.8V$ to $5.5V$, $V_{CCB} = 2.2V$ to $5.5V$, $GND = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$ (unless otherwise noted)^{(1) (2) (3)}

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Propagation delay	SDAB, SCLB	SDAA, SCLA		35		90	ns
t _{PLH}	Propagation delay	SDAA, SCLA	SDAB, SCLB	V _{CCB} ≤ 3V	50		137	ns
t _{PLH}	Propagation delay	SDAA, SCLA	SDAB, SCLB	V _{CCB} > 3V	59		250	ns
t _{PHL}	Propagation delay	SDAB, SCLB	SDAA, SCLA		32		144	ns
t _{PHL}	Propagation delay	SDAA, SCLA	SDAB, SCLB		28		140	ns
t _{TLH} ⁽⁴⁾	Transition time	B side	30%	70%	88			ns
		A side			37			
t _{THL}	Transition time	B side	70%	30%	5.40		32	ns
		A side			1.40		40	
t _{su,en} ⁽⁵⁾	Setup time, EN high before Start condition				100			ns

- (1) Times are specified with loads of $240\ \Omega \pm 1\%$ and $400\ pF \pm 10\%$ on B-side and $240\ \Omega \pm 1\%$ and $200\ pF \pm 10\%$ on A-side. Different load resistance and capacitance alter the rise time, thereby changing the propagation delay and transition times.
- (2) Times are specified with A-side signals pulled up to V_{CCA} and B-side signals pulled up to V_{CCB} .
- (3) Typical values were measured with $V_{CCA} = 0.9\ V$ and $V_{CCB} = 2.5\ V$ at $T_A = 25^{\circ}C$, unless otherwise noted.
- (4) T_{TLH} is determined by the pull-up resistance and load capacitance
- (5) EN should change state only when the global bus and the repeater port are in an idle state

5.7 Typical Characteristics

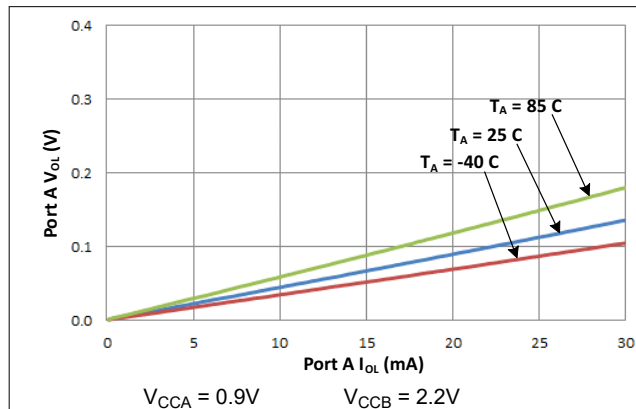


Figure 5-1. Port A V_{OL} vs I_{OL}

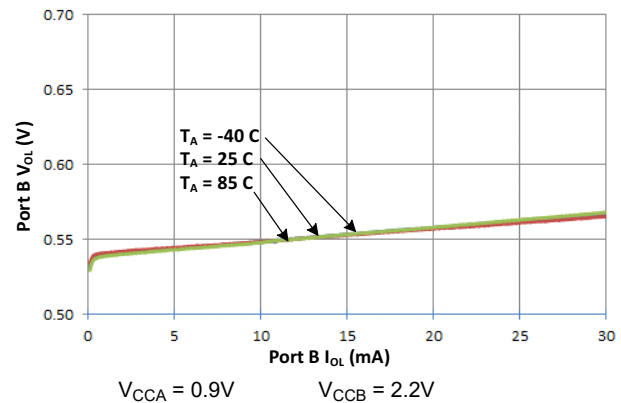


Figure 5-2. Port B V_{OL} vs I_{OL}

Parameter Measurement Information

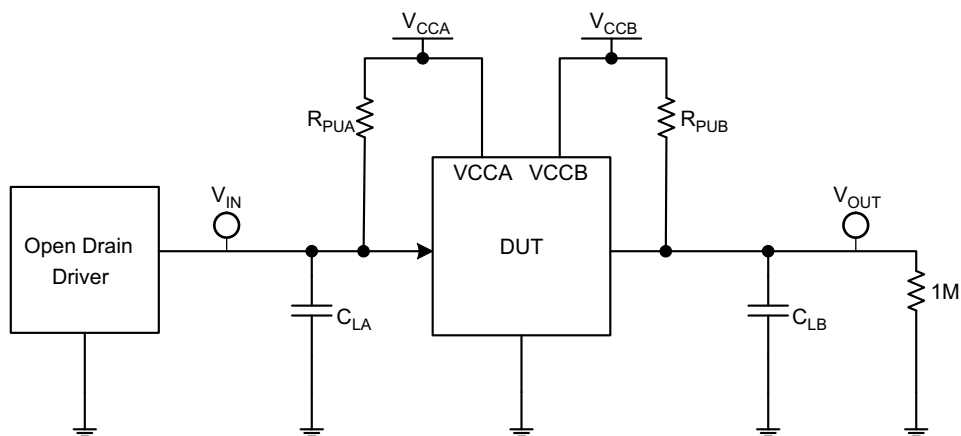
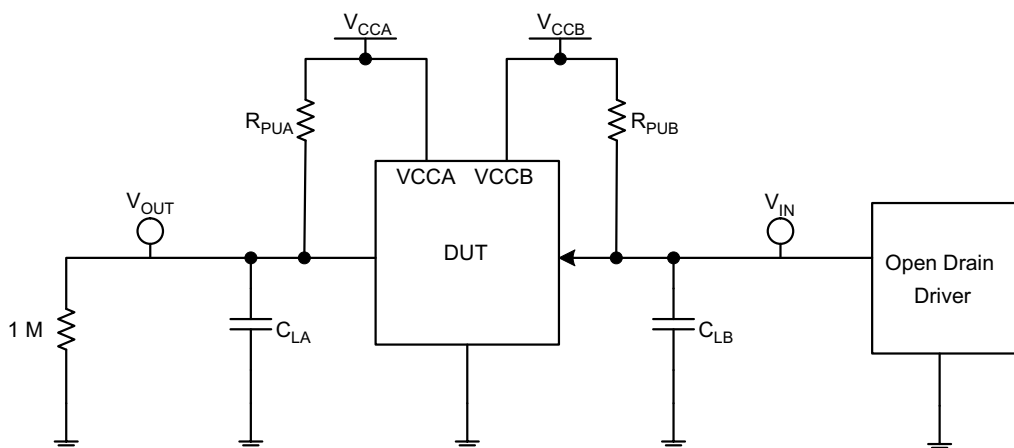


Figure 6-1. Test Circuit for Open-Drain Output from A to B



- A. $V_{CCA} = 0.9V$
- B. $V_{CCB} = 2.5V$
- C. $R_{PUA} = R_{PUB} = 240\Omega$ on the A-side and the B-side
- D. $C_{LA} = 200pF$ on A-side and $C_{LB} = 400pF$ on B-side (includes probe and jig capacitance)
- E. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10MHz$, $Z_O = 50\Omega$, slew rate $\geq 1V/ns$
- F. The outputs are measured one at a time, with one transition per measurement.

Figure 6-2. Test Circuit for Open-Drain Output from B to A

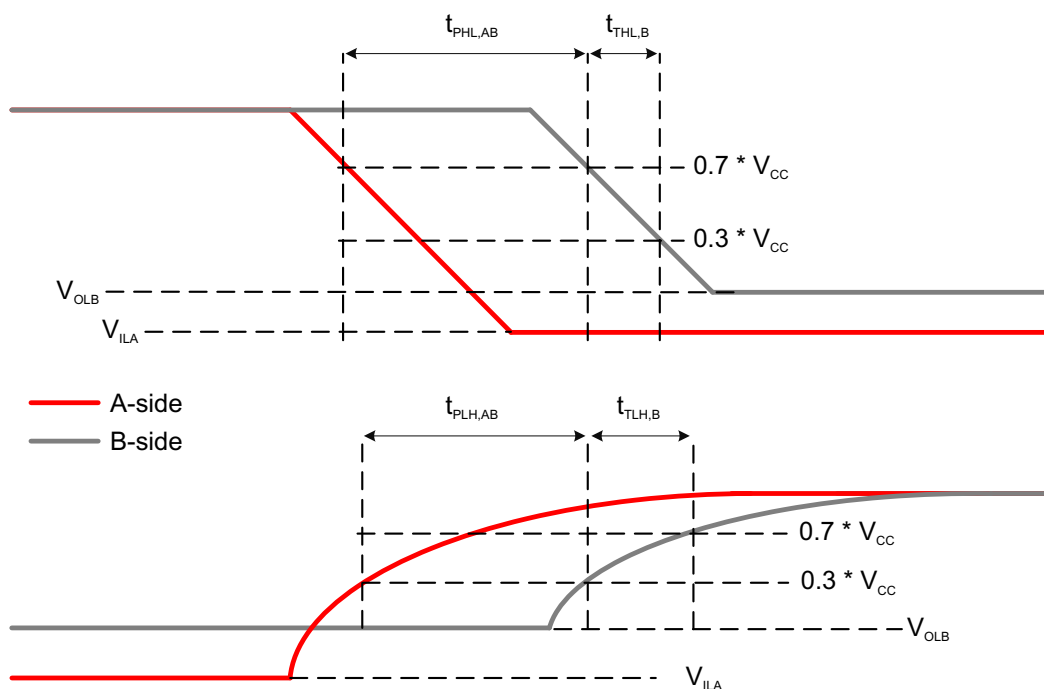


Figure 6-3. Propagation Delay And Transition Times (A to B)

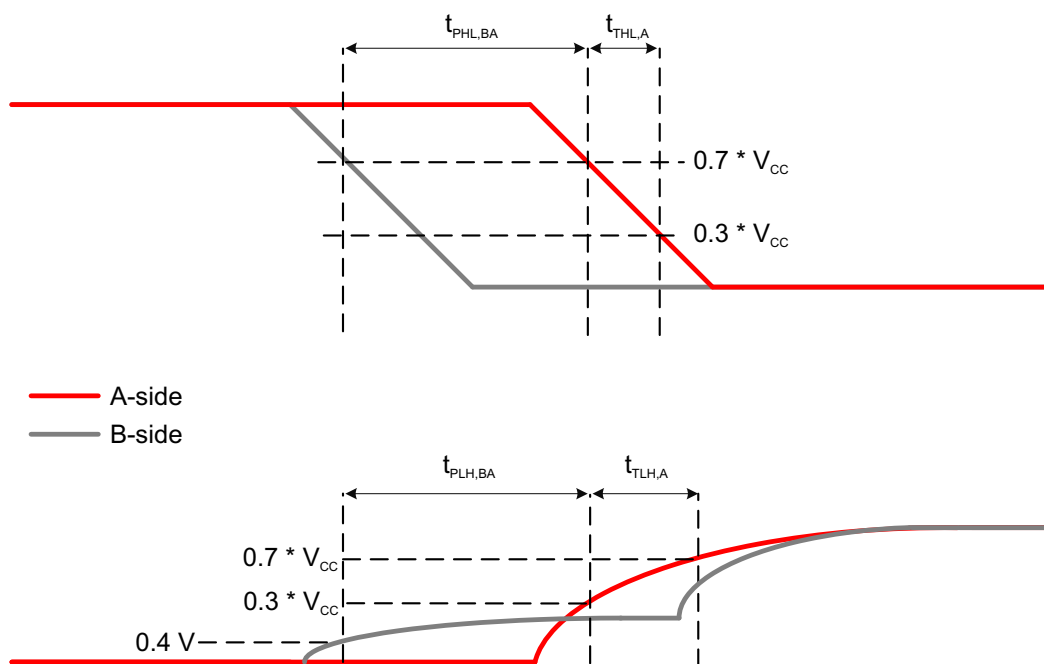


Figure 6-4. Propagation Delay And Transition Times (B to A)

6 Detailed Description

6.1 Overview

The TCA9617B is a BiCMOS dual bidirectional buffer intended for I²C bus and SMBus systems. As with the standard I²C system, pull-up resistors are required to provide the logic high levels on the buffered bus. The TCA9617B has standard open-drain configuration of the I²C bus. The size of these pull-up resistors depends on the system, but each side of the repeater must have a pull-up resistor. The device is designed to work with Standard mode, Fast mode and Fast Mode+ I²C devices. The SCL and SDA lines shall be at high-impedance when either one of the supplies is powered off.

The TCA9617B B-side drivers operate from 2.2V to 5.5V. The output low level for this internal buffer is approximately 0.5V, but the input voltage must be below V_{IL} when the output is externally driven low. The higher-voltage low signal is called a buffered low. When the B-side I/O is driven low internally, the low is not recognized as a low by the input. This feature prevents a lockup condition from occurring when the input low condition is released. This type of design on the B side prevents TCA9617B from being used in series with another TCA9617B B-side or other buffers that incorporate a static or dynamic offset voltage. This is because these devices do not recognize buffered low signals as a valid low and do not propagate the signal as a buffered low again.

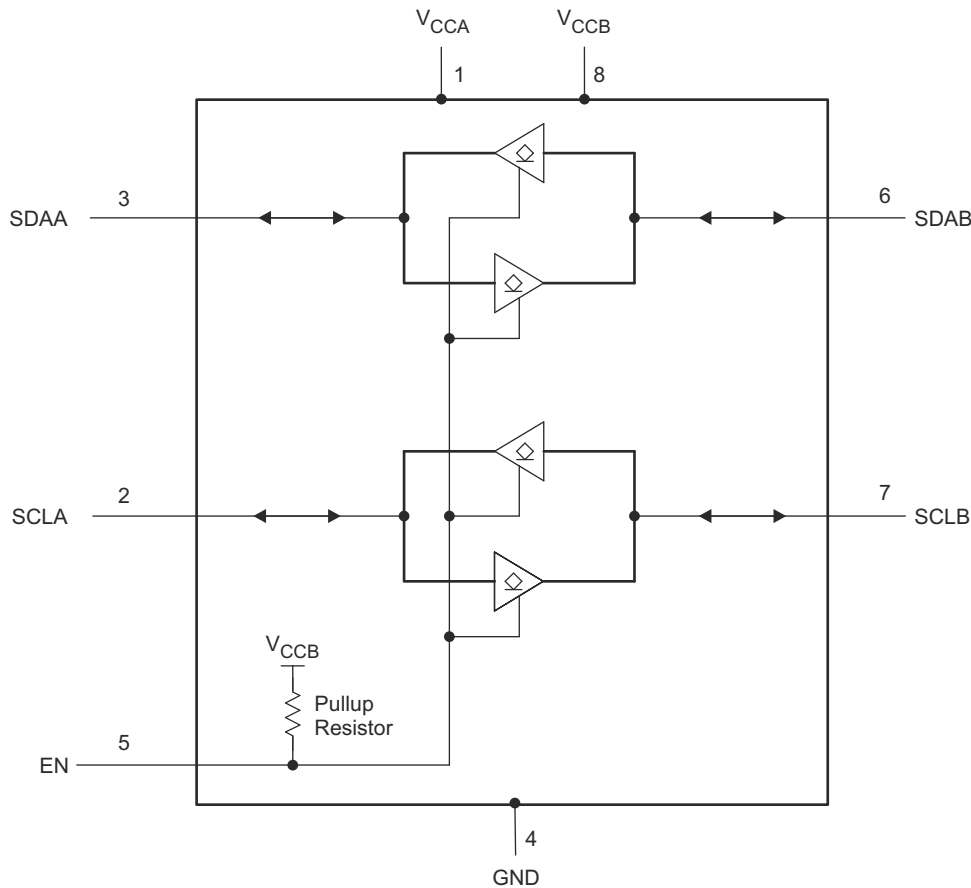
The TCA9617B A-side drivers operate from 0.8V to 5.5V and do not have the buffered low feature (or the static offset voltage). This means that a low signal on the B side translates to a nearly 0V low on the A side, which accommodates smaller voltage swings of low-voltage logic. The output pull-down on the A side drives a hard low, and the input level is set to 30% of V_{CCA} to accommodate the need for a lower low level in systems where the low-voltage-side supply voltage is as low as 0.8V.

The A side of two or more TCA9617B can be connected together to allow a star topology, with the A side on the common bus. Also, the A side can be connected directly to any other buffer with static or dynamic offset voltage. Multiple TCA9617B can be connected in series, A side to B side, with no buildup in offset voltage with only time-of-flight delays to consider.

The TCA9617B includes a power-up circuit that keeps the output drivers turned off until V_{CCB} is above 2V and V_{CCA} is above 0.7V. V_{CCA} is only used to provide references for the A-side input comparators and the power-good-detect circuit. The TCA9617B internal circuitry and all I/Os are powered by the V_{CCB} pin.

After power up and with the EN high, the A side falling below 30% of V_{CCA} turns on the corresponding B-side driver (either SDA or SCL) and drives the B-side down momentarily to 0V before settling to approximately 0.5V. When the A-side rises above 30% of V_{CCA} , the B-side pull-down driver is turned off and the external pull-up resistor pulls the pin high. If the B side falls first and goes below 0.4V, the A-side driver is turned on and drives the A-side to 0V. When the B-side rises above 0.45V, the A-side pull-down driver is turned off and the external pull-up resistor pulls the pin high.

6.2 Functional Block Diagram



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6.3 Feature Description

6.3.1 Bidirectional Level Translation

The TCA9617B can provide bidirectional voltage level translation (up-translation and down-translation) between low voltages (down to 0.8V) and higher voltages (2.2V to 5.5V) in mixed-mode applications.

6.3.2 Low to High Transition Characteristics

Figure 6-2 depicts the offset voltage on the B side of the device. As shown in Figure 6-2 the target releases and the B-side rises, and rises to 0.5V and stays there until the A-side rises above 30% of V_{CCA} . This effect can cause the low level signal to have a *pedestal*. Once the voltage on the A-side crosses 30% of V_{CCA} , the B-side begins to rise to V_{CCB} .

Due to nature of the B-side pedestal and the static offset voltage, there is a slight overshoot as the B-side rises from being externally driven low to the 0.5V offset. The TCA9617B is designed to control this behavior provided the system is designed with rise times greater than 20ns. Therefore; care must be taken to limit the pull-up strength when devices with rise time accelerators are present on the B side. Excessive overshoot on the B-side pedestal can cause devices with rise time accelerators to trip prematurely if the overshoot is more than accelerator thresholds.

6.3.3 High-to-Low Transition Characteristics

When the A side of the bus is driven to 30% of V_{CCA} , the B side driver turns on. This drives the B-side to 0V for a short period (see Figure 6-2), and then the B-side rises to the static offset voltage of 0.5V (V_{OL} of TCA9617B). This effect, called an inverted pedestal, allows the B-side to drive to logic low much faster than driving to the static offset. Driving to the static offset voltage requires that the fall time be slowed to prevent ringing.

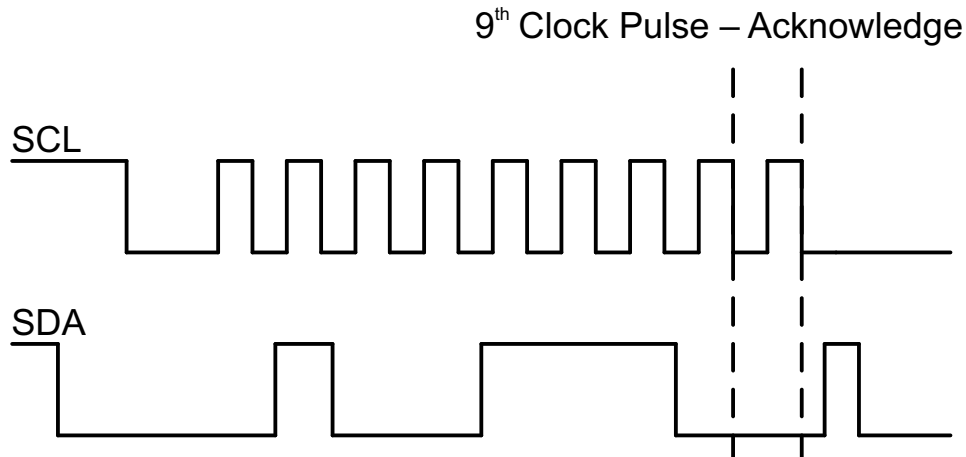


Figure 6-1. Bus A (0.8V to 5.5V Bus) Waveform

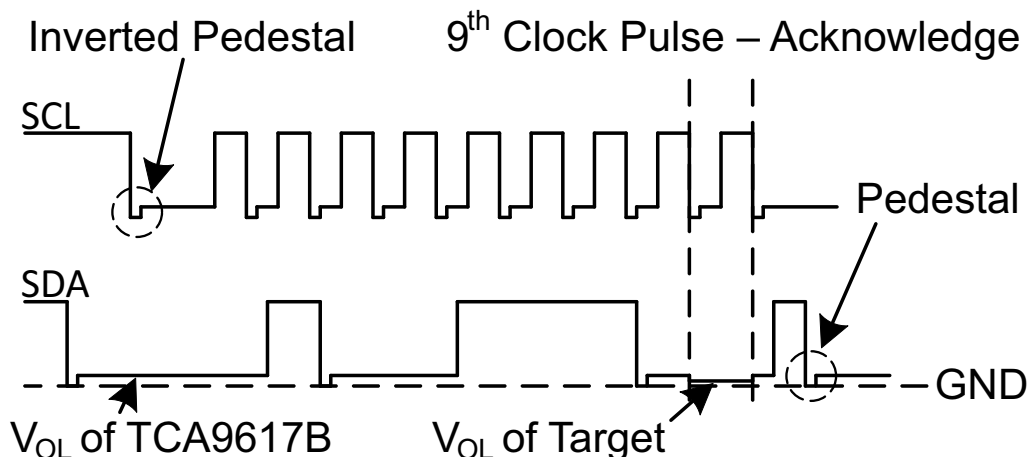


Figure 6-2. Bus B (2.2V to 5.5V Bus) Waveform

6.4 Device Functional Modes

The TCA9617B has an active-high enable (EN) input with an internal pull-up to V_{CCB} , which allows the user to select when the repeater is active. This can be used to separate a misbehaving target on power-up reset. The EN must never change state during an I²C operation. Disabling during a bus operation can hang the bus. Enabling part way through the bus cycles can confuse the I²C parts being enabled. The EN input must change state only when the global bus and repeater port are in the idle state to prevent system failures.

Table 6-1. Function Table

INPUT EN	FUNCTION
L	Outputs disabled
H	SDAA = SDAB SCLA = SCLB

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

A typical application is shown in [Figure 7-1](#). In this example, the system controller is running on a 0.9V I²C bus, and the target is connected to a 2.5V bus. Both buses are running at 400kHz. Decoupling capacitors are required, but are not shown in [Figure 7-6](#) for simplicity.

The TCA9617B is 5V tolerant so no additional circuits are required to translate between 0.8V to 5.5V bus voltages and 2.7V to 5.5V bus voltages.

When the A side of the TCA9617B is pulled low by a driver on the I²C bus, a comparator detects the falling edge when the signal level goes below 30% of V_{CCA} and cause the internal driver on the B side to turn on. The B-side is first pulled down to 0V, and then settles to 0.5V. When the B side of the TCA9617B falls below 0.4V, the TCA9617B detects the falling edge, turn on the internal driver on the A side and pull the A-side pin down to ground.

On the B-side bus of the TCA9617B, the clock and data lines has a positive offset from ground equal to the V_{OL} of the TCA9617B. After the eighth clock pulse, the data line is pulled to the V_{OL} of the target device, which is close to ground in this example. At the end of the acknowledge, the level rises only to the low level set by the driver of the TCA9617B for a short delay (approximately 0.5V), while the A-side bus rises above 30% of V_{CCA} and then continues high.

Although the TCA9617B has a single application, the device can exist in multiple configurations. [Figure 7-1](#) shows the standard configuration for the TCA9617B. Multiple TCA9617Bs can be connected either in star configuration ([Figure 7-4](#)) or in series configuration ([Figure 7-5](#)). The design requirements, detailed design procedure, and application curves in [Section 7.2.1](#) are valid for all three configurations.

7.2 Typical Application

7.2.1 Standard Application

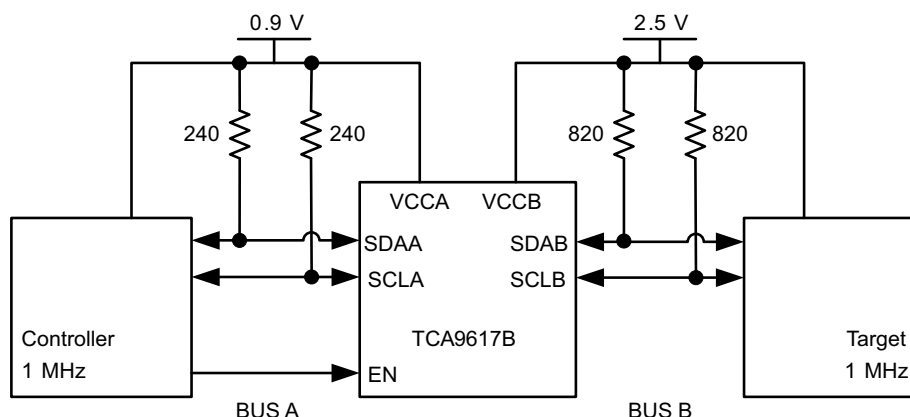


Figure 7-1. Bidirectional Voltage Level Translator

7.2.1.1 Design Requirements

For the level-translating application, the following must be true:

- $V_{CCA} = 0.8V$ to $5.5V$
- $V_{CCB} = 2.2V$ to $5.5V$
- $V_{CCA} \leq V_{CCB}$
- $I_{OL} > I_O$

7.2.1.2 Detailed Design Procedure

7.2.1.2.1 Pullup Resistor Sizing

For the TCA9617B to function correctly, all devices on the B-side must be able to pull the B-side below the voltage input low contention level ($0.4V$). This means that the V_{OL} of any device on the B-side must be below $0.4V$ for proper operation.

The V_{OL} of a device can be adjusted by changing the I_{OL} through the device which is set by the pull-up resistor value. The pull-up resistor on the B-side must be carefully selected to make sure the logic levels are transferred correctly to the A-side.

The B-side pull-up resistor sizing must also make sure that the rise time is greater than $20ns$. Shorter rise times increase the pedestal overshoot shown in [Figure 7-2](#).

7.2.1.3 Application Curves

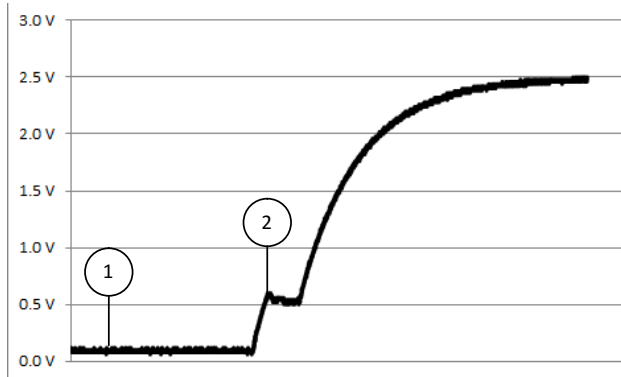


Figure 7-2. B-side Pedestal

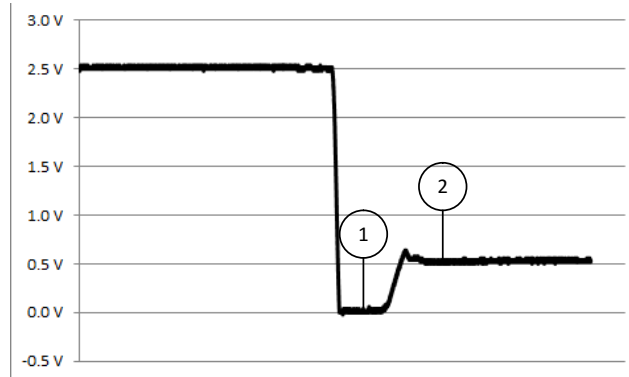


Figure 7-3. B-side Inverted Pedestal

7.2.2 Star Application

Multiple A sides can be connected in a star configuration, allowing all nodes to communicate with each other.

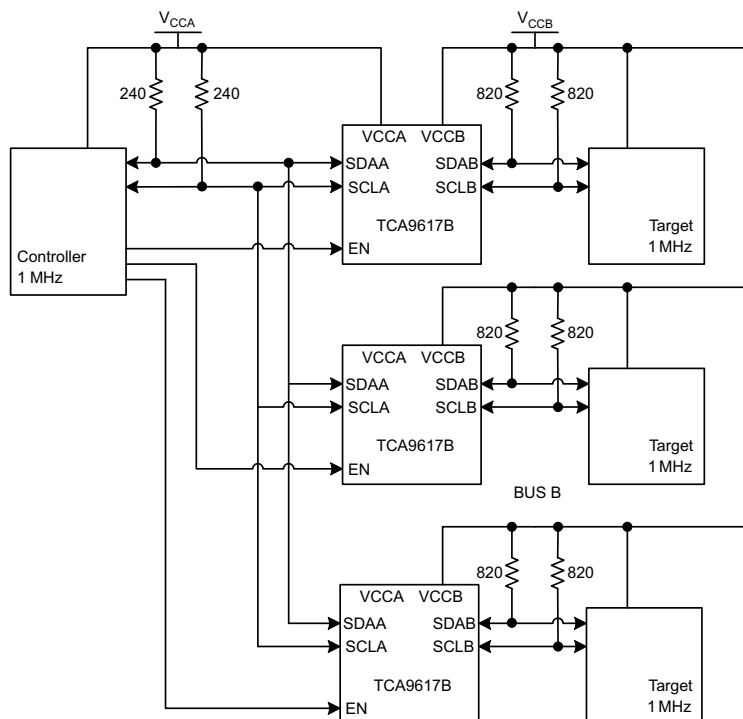


Figure 7-4. Typical Star Application

7.2.2.1 Design Requirements

Refer to [Section 7.2.1.1](#).

7.2.2.2 Detailed Design Procedure

Refer to [Section 7.2.1.2](#).

7.2.2.3 Application Curves

Refer to [Section 7.2.1.3](#).

7.2.3 Series Application

Multiple TCA9617Bs can be connected in series as long as the A side is connected to the B side. I²C bus target devices can be connected to any of the bus segments. The number of devices that can be connected in series is limited by repeater delay/time-of-flight considerations on the maximum bus speed requirements.

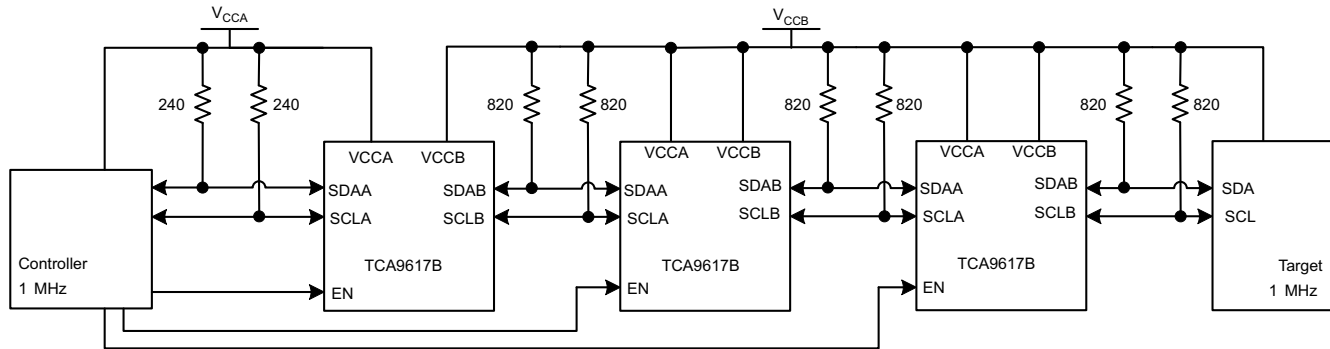


Figure 7-5. Typical Series Application

7.2.3.1 Design Requirements

Refer to [Section 7.2.1.1](#).

7.2.3.2 Detailed Design Procedure

Refer to [Section 7.2.1.2](#).

7.2.3.3 Application Curves

Refer to [Section 7.2.1.3](#).

7.3 Power Supply Recommendations

For VCCA, an 0.8V to 5.5V power supply is required. For VCCB, a 2.2V to 5.5V power supply is required.

Standard decoupling capacitors are recommended. These capacitors typically range from 0.1 μ F to 1 μ F, but the value of the capacitance depends on the frequencies of noise from the power supply.

7.4 Layout

7.4.1 Layout Guidelines

The recommended decoupling capacitors must be placed as close to the VCCA and VCCB pins of the TCA9617B as possible.

7.4.2 Layout Example

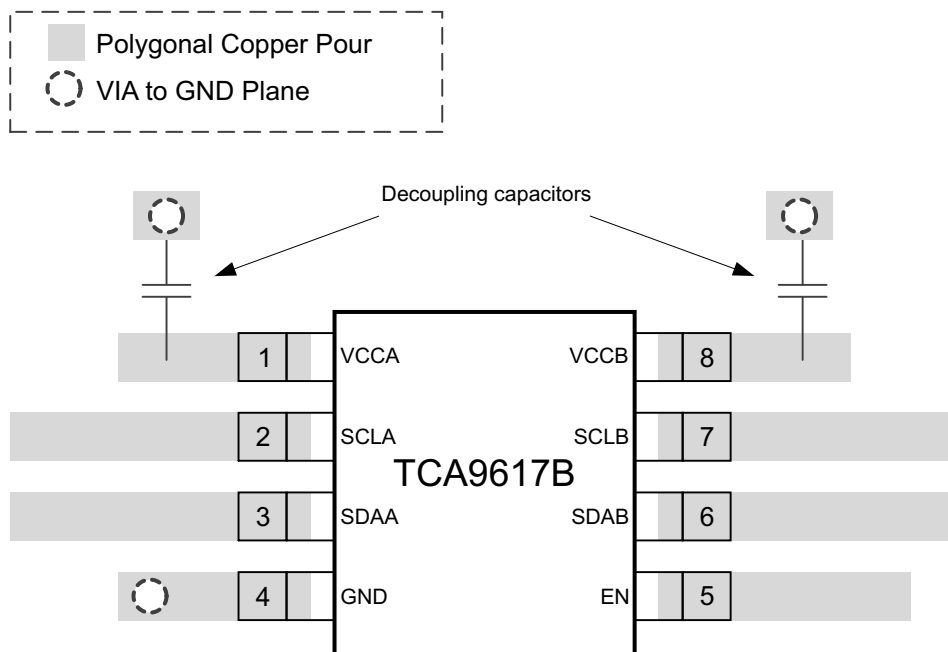


Figure 7-6. Layout Schematic

8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

8.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

[TI Glossary](#)

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

Changes from Revision B (December 2018) to Revision C (January 2024)	Page
• Changed all instances of legacy terminology to controller and target where mentioned.....	1
• Added weak pull-up resistor information on pin EN	3
• Changed abs max voltages from 7V to 6.5V.....	4
• Changed the Thermal Information for 8 DGK.....	5
• Changed V_{IK} MAX value of -1.2V to a MIN value.....	5
• Changed T_{PLH} (B to A) by removing typical value.....	7
• Changed T_{PLH} (A to B) for $V_{CCB} \leq 3V$ by changing min value from 59ns to 50ns and removing typical value.....	7
• Changed T_{PLH} (A to B) for $V_{CCB} > 3V$ by removing typical value.....	7
• Changed T_{PHL} (B to A) by changing min value from 69ns to 32ns and removing typical value.....	7
• Changed T_{PHL} (A to B) by changing min value from 68ns to 28ns and removing typical value.....	7
• Changed T_{THL} (B side) by changing max value from 13.8ns to 32ns and removing typical value.....	7
• Changed T_{THL} (B side) by changing max value from 11.3ns to 40ns and removing typical value.....	7
• Changed 0.3V _{CCA} to: 30% of V _{CCA} in the Overview	10
• Changed A side falling below 0.7V _{CCA} to: A side falling below 30% of V _{CCA}	10
• Changed goes below 0.7V _{CCB} to: goes below 0.4V	10
• Changed 0.3V _{CCA} to: 30% of V _{CCA} in the Low to High Transition Characteristics	11
• Deleted <i>Since the A-side does not have a static offset low voltage, no pedestal is seen on the A-side as shown in Figure 6-1</i>	11
• Changed 0.7V _{CCA} to 30% of V _{CCA} in the High-to-Low Transition Characteristics	12
• Changed <i>isolate a badly behaved</i> to <i>separate a misbehaving</i> in the Device Functional Modes	12
• Changed 0.7V _{CCA} to 30% of V _{CCA} in the Application Information	13
• Changed falls below 0.45V to: falls below 0.4Vt.....	13
• Changed (0.45V) to: (0.4V) in the Pullup Resistor Sizing	14
Changes from Revision A (December 2014) to Revision B (December 2018)	Page
• Changed the appearance of the DGK pin out image	3
• Changed $V_{CCA} < V_{CCB}$ To: $V_{CCA} \leq V_{CCB}$ in the Design Requirements list.....	14
Changes from Revision * (December 2014) to Revision A (December 2014)	Page
• Initial release of full version.	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TCA9617BDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG SN	Level-1-260C-UNLIM	-40 to 85	ZBOK	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

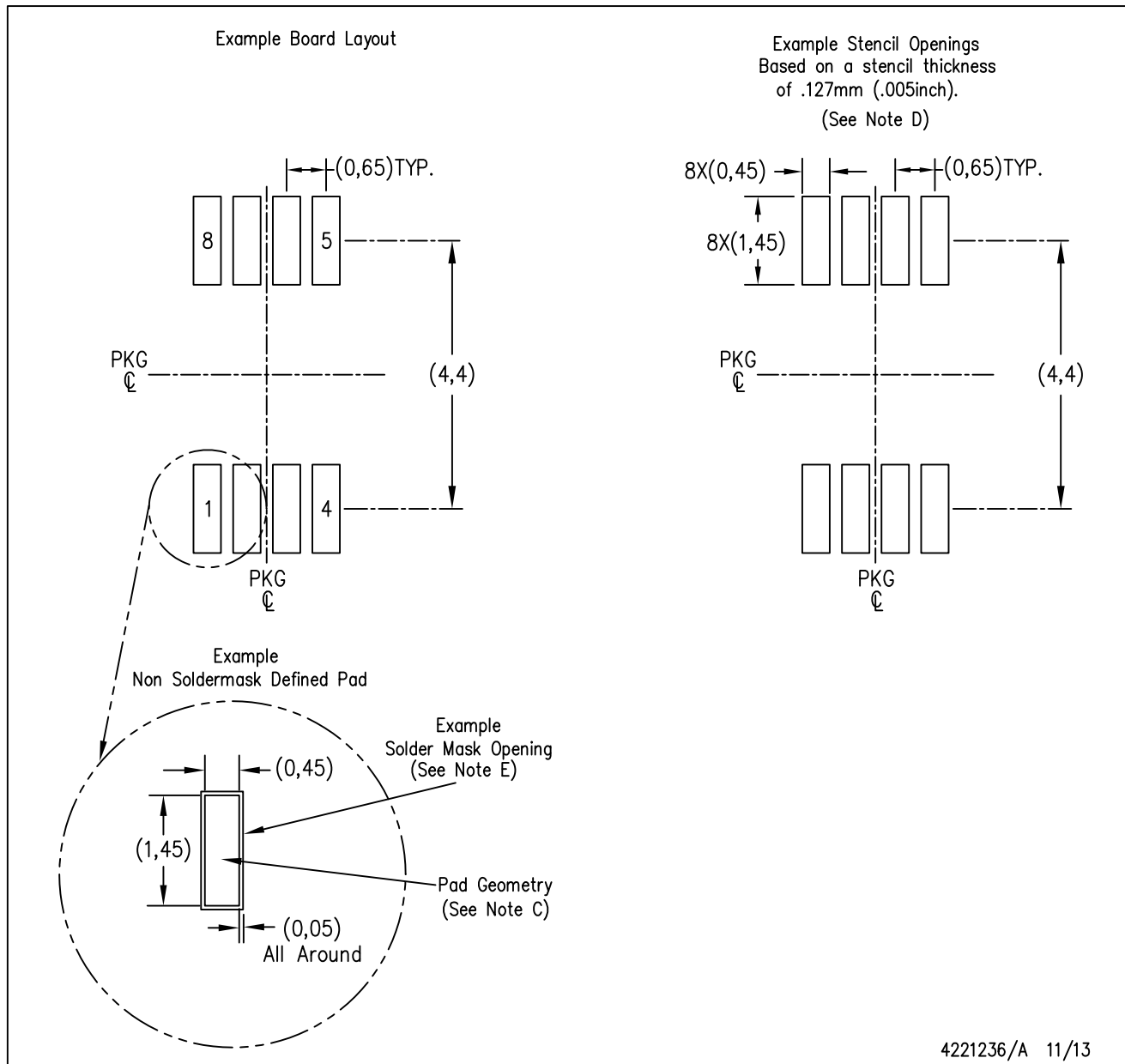


NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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